

Electroluminescence as a probe of strong exciton-plasmon coupling in few-layer WSe₂

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Abstract

The manipulation of coupled quantum excitations is of fundamental importance in realizing novel photonic and optoelectronic devices. We use electroluminescence to probe plasmon-exciton coupling in hybrid structures each consisting of a nanoscale plasmonic tunnel junction and few-layer two-dimensional transition-metal dichalcogenide transferred onto the junction. The resulting hybrid states act as a novel dielectric environment to affect the radiative recombination of hot carriers in the plasmonic nanostructure. We determine the plexcitonic spectrum from the electroluminescence and find Rabi splittings exceeding 25 meV, near the onset of strong coupling. Our experimental findings are supported by electromagnetic simulations that enable us to explore systematically, and in detail, the emergence of plexciton polaritons as well as the polarization characteristics of their far-field emission. Electroluminescence modulated by plexciton coupling provides potential applications for engineering compact photonic devices with tunable optical and electrical properties.

Introduction

It is well known that two oscillators can couple together to generate new normal modes through the exchange of energy. The same analogy applies to quantum emitters, or emitter ensembles, when placed inside an optical cavity, sustaining photonic or plasmonic modes¹. In the weak coupling regime, their spontaneous emission rate is modified by the density of electromagnetic (EM) states inside the cavity^{2,3}. From optical interactions with the emitter(s)^{4,5}, the cavity spectrum may develop a dip at the excitonic frequency (exciton-induced transparency) which becomes more apparent in the strong coupling regime^{6,7}. Polaritonic mixed states emerge that are part light, part

matter, and the cavity spectrum undergoes Rabi splitting into two separate polariton branches. The optical response of the strongly coupled system is highly sensitive to the state of the photon emitter(s)⁷, which provides a means of manipulating quantum states of light and can enable high-fidelity quantum operations⁸⁻¹⁰ and nonclassical photon generation^{11,12}.

Transition metal dichalcogenides (TMDs) are ideal materials for coupling to optical resonators, as TMDs interact strongly with light through sharp excitonic modes with high binding energies of a few 100 meV even at room temperature¹³, particularly in the monolayer limit¹⁴⁻¹⁷. Embedding the strong dipole moment of these optical transitions in electromagnetic (EM) resonators has enabled the formation of hybrid, polariton states whose matter component are TMD excitons¹⁸. Accessing individual strongly coupled emitters has been limited largely to far-field optical probes under diffraction-limited light beams¹⁹⁻²², which impedes miniaturization and large scale integration for practical applications. Electrically driven plasmonic nanostructures can potentially be leveraged to provide a feasible route to realize and probe nanoscale strong coupling phenomena. By placing exciton-supporting ultrathin TMDs in close proximity to localized surface plasmons (LSPs) controlled by pure electrical means, it is possible to access the LSP near field, opening new possibilities for the tuning, study and functionality of strongly coupled nanoscale systems. Near-field electrical probes are a promising tool to characterize polaritonic physics in TMD platforms, where the bright emission from uncoupled excitons makes challenging extracting the far-field signal from the strongly coupled ones by using conventional optical methods.

Here, leveraging an electrically driven atomic-scale light source²³⁻²⁵, we show that the onset of the strong coupling regime in the interaction between TMD excitons and localized plasmonic resonances²⁶ can be detected by means of a pure electrically driven excitation. The sub-nm sized gap between the two metallic electrodes serves as an ultra-confined plasmonic nanocavity where

incoherent photons are generated. In this novel system, the plexciton polaritons strongly modify the radiative local density of states that governs light emission from hot carriers in the driven plasmonic metal. The light emission process thus provides an extremely local probe of polariton physics in the near field. Measured spectra are in excellent agreement with a theoretical model parameterized through electromagnetic simulations describing the coupling of LSPs and TMD excitons, building the connection between the nanoscale hot carrier dynamics and far field radiative photons. These findings open new paths towards the design of compact solid-state quantum light sources and strong coupling-based control of hot carriers in plasmonic nanostructures.

Using standard e-beam lithography techniques, we have generated gold nanowire samples on an oxidized Si wafer. WSe₂-coupled nanowires are then formed by employing a dry transfer method. At 30 K, an electromigration technique^{23,27} is used to break the wire and form a plasmonically active tunneling nanogap that supports LSP resonances (detailed process and measurement description is in Methods). A 3D sketch of the setup and a brief schematic showing the coupling mechanics are illustrated in Fig.1a. An example electroluminescence (EL) spectrum, obtained at 0.8-0.9 V applied bias from a bare tunnel gap *without* WSe₂, is shown in Fig. 1b. At low currents the origin of the photon emission from a biased nanogap is generally attributed to the radiative decay of the electrically excited surface plasmon modes. These plasmon resonances are excited as tunneling electrons inelastically scatter with the plasmonic modes of the nanojunction. In the low current limit, individual tunneling electrons should only excite optical modes up to a cutoff energy given by the applied bias eV , leading to the “below-threshold” light emission ($\hbar\omega \leq eV$)²⁸⁻³¹. Continuum emission at energies higher than eV implies that another mechanism also contributes to the far-field of the nanostructure: the plasmon-enhanced radiative recombination of

hot carriers (electrons and holes) in the vicinity of the tunnel junction in the high current limit^{23–25,29,31–33}. In this mechanism, the EL spectrum embeds the rich plasmon mode structure of the system. The broad peak that appears at around 1.69 eV (~ 0.3 eV line width) can be assigned to a plasmon resonance associated with the dipolar optically bright mode of the metal nanowire^{23,34}. The photoluminescence (PL) from a bare bilayer WSe₂, excited by a 532 nm laser, is also plotted in Fig. 1b. The sharp peak appearing at 1.68 eV corresponds to the direct A exciton transition energy, consistent with previous studies^{35–37}. The spectral overlap between the broadened EL peak and the PL exciton opens the way towards the emergence of strong light-matter coupling phenomena in the hybrid system.

An image of the TMD-coupled plasmonic junction structure is shown in Fig. 1c, where the WSe₂ flake covers the whole nanogap area including the extended larger electrodes. A color map of the A exciton peak in the WSe₂ PL signal is plotted in Fig. 1d, revealing the location of the gold electrodes and the nanogap emitting region. An optical microscope image of the hybrid structure right after dry transfer for WSe₂ is shown in Fig. S1 in supplemental information. Due to the reflectivity of the gold electrodes, the PL signal is stronger on the electrodes than on the SiO₂-Si substrate. The thickness of the transferred WSe₂ flake is characterized using the atomic force microscopy (AFM), as can be seen in Fig. 1e, which corresponds to the boxed area on the edge of the WSe₂ flake in Fig. 1c. The height profile shown in the lower part of Fig. 1e was taken along the red dashed line above, revealing a thickness of ~ 3.9 nm for bilayer WSe₂, also in agreement with previous studies³⁷.

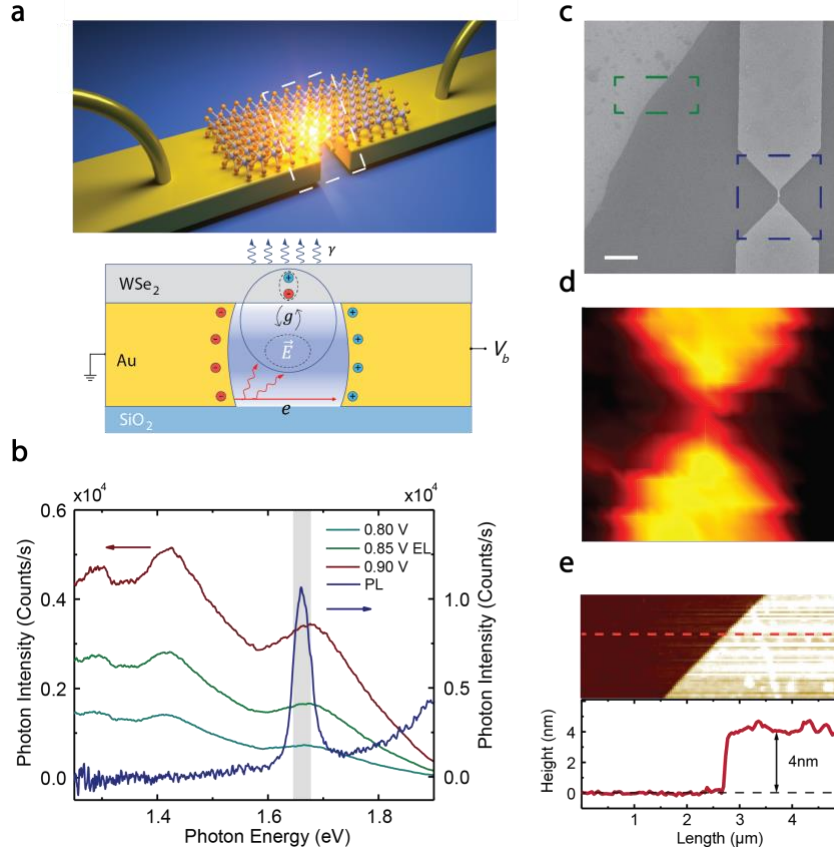


Figure 1. Schematics of experimental setup and various characterization for the TMD and EL spectrum. (a) schematic of a fabricated hybrid TMD-on-gap structure and the diagram of plasmon-exciton coupling connected to electrically driven tunneling within the gap. (b) EL spectral measurements for a bare gold junction at different biases with a zero-bias conductance of $0.11 G_0$, plotted together with the PL spectra for a bilayer of WSe₂. Shaded area indicates the full width at half maximum of the A exciton peak. (c) Electron microscopy image of an electromigrated junction with TMD on top. The scale bar in the figure is 2 μm . (d) PL mapping of the A exciton peak of the area for the area in (c) enclosed by the blue dotted lines. (e) AFM image of the transferred TMD edge indicated by the green dotted lines in (c). Below shows the cross-section height profile of the red dashed line.

When the coupled TMD-nanogap structure is biased to the EL regime, we observe two peaks instead of a single broad and bright plasmonic resonance, reproducing the Rabi splitting phenomenology of strongly coupled systems (Fig. 2a). These two peaks emerge around 1.69 eV, associated with two plexcitonic-like states that result from the coupling between the local plasmon modes of the junction and the excitons in the WSe₂ flake. This device shows a spectral separation of 50 meV, which allows us to estimate a collective plasmon-exciton coupling strength of around 25 meV¹. Doublet spectra for different bias voltages are shown together with the PL spectrum for

the A exciton of this flake of WSe₂, highlighting the correspondence between the exciton peak and the position of the dip in the coupled samples. We have also used MoS₂ as an alternative for WSe₂ to form a TMD-gap system with a blue-tuned plasmonic resonance (narrower nanowire width) to accommodate the higher exciton energy (~1.9 eV). Analogous polaritonic spectra can be observed, as shown in Fig. S2 in Supplemental Information (SI).

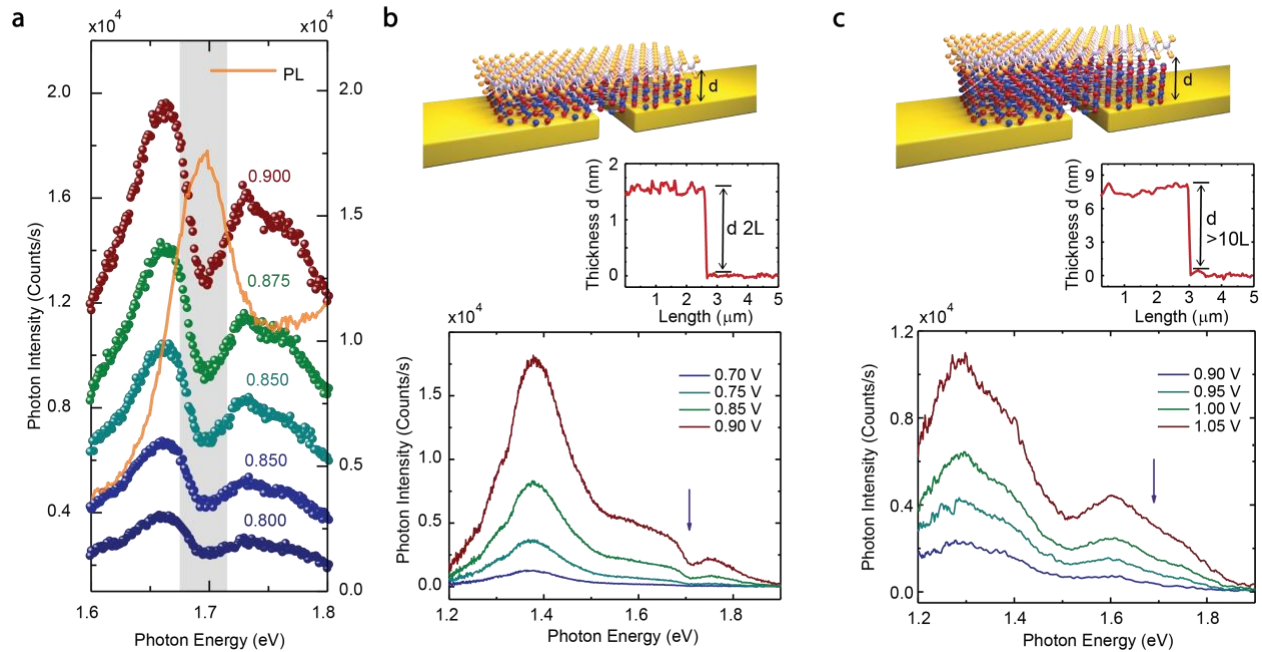


Figure 2. Spectral measurements of EL spectra for the hybrid TMD-on-gap structure and the spaced-by-hBN structures with different hBN thickness. (a) Measured EL spectra at different biases from 0.8 V to 0.9 V with a zero-bias junction conductance of $0.20 G_0$, plotted together with the PL spectrum measured for the WSe₂ on top. (b) Measured EL spectra for the TMD-on-gap structure with bilayer hBN between the WSe₂ and the gold nanogap, from 0.7 V to 0.9 V ($0.15 G_0$ zero-bias conductance). The WSe₂ A exciton peak energy is indicated by the purple arrow. Height profile of the encapsulated hBN is shown in the middle inset. (c) Measured EL spectra at different biases from 0.9 V to 1.05 V with encapsulated more than 10 layers of hBN between the WSe₂ and the gold nanogap ($0.27 G_0$ zero-bias conductance). At this greater spacing between the TMD and the nanogap, the plasmon-exciton coupling is too small to lead to detectable spectral signatures.

Numerical simulations (described below) show that the system behind the spectral features in Fig. 2a is approaching the onset of strong-coupling and the formation of plexciton polaritons, rather than the spectral dip arising from optical absorption of the TMD exciton transition. This

conclusion is further supported by the EL measurements presented in Fig. S3 in SI, which correspond to samples with WSe₂ flakes of different thicknesses. These reveal that the doublet profile only develops for few-layer (less than 4) WSe₂ samples, while exciton absorption would become stronger with increasing TMD thickness. To investigate the plasmon-exciton coupling further in our samples, control experiments were performed in which hexagonal boron nitride (hBN) layers were introduced as a spacer between the nanogap and the WSe₂. As shown in the sketches in Fig. 2b and 2c above, exfoliated hBN with two thicknesses (d) were encapsulated in between the TMD and the gold nanowire using the dry transfer procedure described in Methods. Fig. 2b plots the emission spectra for different bias voltages and for a 2-layer-thick hBN spacer, which is verified by the AFM height profile in the middle³⁸. The emission dip at 1.7 eV, matching the measured A exciton energy of transferred WSe₂, is apparent and indicated by the purple arrow, although its contrast has been strongly reduced with respect to Fig. 2a. As shown in Fig. 2c, for hBN thicknesses larger than 10 layers, the measured spectra do not show any splitting feature, suggesting that the plasmon interaction with the TMD excitons is too weak in this geometry. Note that the spectra in Fig. 2b and c, despite the fabrication constraints and the lack of control on the geometry of the electromigrated gold junctions, are very similar at frequencies well below the WSe₂ exciton transition. These hBN-related results indicate that the plasmon modes sustained by the gold nanostructure are strongly localized at the junction and present a decay length along the vertical direction of only a few nanometers, which is also confirmed by the simulation results below.

To understand how the plasmon-exciton coupling is manifested through electrically driven hot carrier light emission, we have performed normalization analysis on the measured EL spectra to extract the radiative local density of states $\rho(\omega)$ of the hybrid TMD on the gap system, based on

previous work^{23,31} (The detailed process is described in SI section 1). As can be seen in Fig. S4, the extracted $\rho(\omega)$ in the energy range for the polaritons all collapse perfectly for different biases, just as in the spectral range that is unaffected by the exciton. Such consistency validates that the emission spectrum scales as the product of a polariton-modified $\rho(\omega)$ and a voltage-dependent hot carrier Boltzmann distribution. Our results also confirm that by introducing excitonic states in the near field of a plasmonic nanostructure, one can manipulate the energy decay route of the electrically generated hot carriers. Notice that this mechanism of plasmonic metal hot carrier electroluminescence coupled into a polariton-modified $\rho(\omega)$ is distinct from and complementary to the generation of exciton luminescence via plasmon-exciton resonant energy transfer³⁹.

To gain physical insight into the observed plasmon-exciton coupling phenomenology, we have performed numerical simulations with the frequency-domain Maxwell's Equation solver implemented in COMSOL Multiphysics. Our EM model mimics the geometrical dimensions of the experimental samples with the metal permittivity taken from previous work⁴⁰ (Detailed modeling can be found in Methods). Optical properties of WSe₂ are modelled through a Clausius–Mossotti anisotropic dielectric function⁴¹ that assumes that the exciton dipolar moments are oriented in-plane of the TMD layer. Thus, we have in- and out-of-plane permittivity components of the form $\varepsilon_{||}(\omega) = \varepsilon_b \frac{1+2\beta(\omega)}{1-\beta(\omega)}$ and $\varepsilon_{\perp}(\omega) = \varepsilon_b$, respectively, with

$$\beta(\omega) = \frac{\mu_{tmd}^2}{3\varepsilon_0\hbar} \rho_{tmd} \frac{2\omega_{tmd}^2}{\omega_{tmd}^2 - (\omega + i\gamma)^2} \quad (1)$$

where the different constants were obtained from the fitting to the experimental data in Ref. ¹⁴. Thus, $\varepsilon_b = 18$ is the background permittivity, and the exciton transition frequency, ω_{tmd} , and linewidth, γ , were set to 1.7 eV and 10 meV, respectively. Real and imaginary parts of the in- and out-of-plane WSe₂ permittivity are shown in the inset of Fig. 3a. Notice that such a small value for γ implies that the excitonic contribution to the real and imaginary parts of $\varepsilon_{||}(\omega)$ is relevant only

within a spectral band of 10 meV. The weight of the exciton dipole moment and exciton density is given by $\mu_{tmd}^2 \rho_{tmd} = 10^{-4} \text{ e}^2/\text{nm}$. These values are in agreement with recent studies⁴².

Adapting the phenomenological expression obtained from previous experiments on hot carrier EL^{23,31}, we define the numerical far-field emission intensity as

$$I_{ff}(\omega) = \omega^4 \rho_{rad}(\omega) \exp\left(-\frac{\hbar\omega}{k_B T_{eff}}\right) \quad (2)$$

where $\rho_{rad}(\omega)$ is the local density of radiative photonic states at the electron tunnelling light source, obtained from our numerical calculations of the radiative Purcell factor, and $T_{eff} = 1400 \text{ K}$ ²³. Fig. 3a plots the emission spectrum obtained from the numerical simulations (solid line). We can observe that the numerical results reproduce the experimental features, even the strong peak at low frequencies (1.3 eV) that is apparent in Fig. 2b and c. Most importantly, in remarkable agreement with the experiments, $I_{ff}(\omega)$ presents an asymmetric doublet-like feature at higher frequencies, with an emission dip at 1.7 eV, which originates from the coupling of the WSe₂ exciton with a LSP mode spectrally located at around 1.6 eV.

We further employ our EM model to perform a systematic analysis of the plasmon-exciton coupling strength to identify in which light-matter coupling regime (weak or strong) our device is operating. Fig. 3b and c presents two different studies that investigate whether the strong-coupling regime is reached, and well-developed plexciton polariton states are formed in the experimental samples. Figure 3b presents the usual anti-crossing map broadly employed in the literature to identify the onset of strong coupling. In our calculations, we swept the WSe₂ exciton frequency from 1.4 to 2 eV, keeping the rest of the model parameters, and therefore the plasmon frequency, fixed. Black dotted lines plot both frequencies. We fitted the numerical emission map to the expression of the intensity spectrum obtained for a simplified model consisting of a single excitonic emitter interacting with a single plasmonic resonance⁶. Note that this depends only on 5

variables, the plasmon and exciton frequencies and linewidths, as well as their interaction strength. As a result of the fitting, we extracted a plasmon-exciton coupling strength $g = 31$ meV, in agreement with the experimental values.

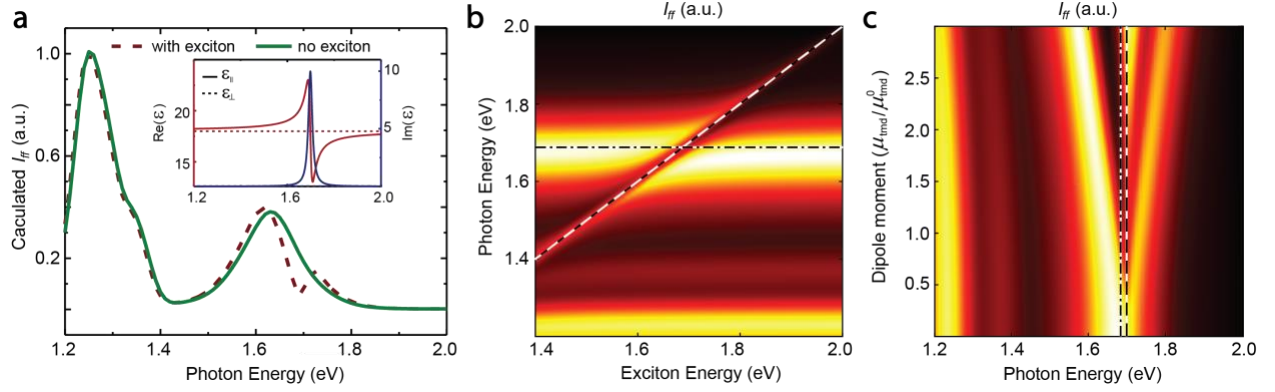


Figure 3: (a) Numerical emission spectrum, $I_{ff}(\omega)$, for the model TMD-plasmonic system. Solid (dashed) line corresponds to calculations including (excluding) the excitonic contribution to the WSe2 permittivity. Inset: WSe₂ permittivity (real and imaginary parts) as utilized in our electromagnetic model. (b-c) Numerical results for the emission I_{ff} maps by sweeping the model exciton frequency (b), and dipole moment (c). The colors code the far-field intensity from minimum (black) to maximum (yellow) in linear, thermal color scale.

Panel c of Fig. 3 presents a similar study, but now sweeping the exciton dipole moment. The value taken in the TMD permittivity in Fig. 3a is labelled as μ_{tmd}^0 . For $\mu_{tmd} \ll \mu_{tmd}^0$, the spectrum presents a single peak at 1.7 eV, a dip emerges with increasing dipole moment, initially due to exciton absorption and subsequently, because of polariton formation. For $\mu_{tmd} \gg \mu_{tmd}^0$, two polariton branches are clearly apparent, and another emission peak emerges in between the Rabi doublet. This feature can be attributed to the light scattered by WSe₂ excitons that remain uncoupled to the plasmon resonance, described through a strong variation in the real part of $\epsilon_{||}(\omega)$ in our model. Such a small peak feature at the exciton energy can also be seen in measured polarized spectra shown in Fig. S6. The fitting of this numerical map yields the same plasmon-exciton coupling strength as the previous one at $\mu_{tmd} = \mu_{tmd}^0$. The surface plasmon linewidth extracted from both maps is $\gamma_{SP} = 90$ meV, which allows us to conclude that the experimental

samples are approaching the onset of plasmon-exciton strong coupling, usually taken as $2g = \gamma_{SP}$ (neglecting the detuning between plasmon and exciton energies). Figure S7 presents a numerical study that, in agreement with the experimental results in Fig. 2, predicts the vanishing of plexcitonic spectral signatures through a dielectric spacer between TMD and metal nanowire.

Past studies on the plasmonic properties of tunnel junctions in the absence of TMDs reveals rich spectral mode features with different modes dominating at different detected polarizations^{23,34} due to hybridization at the nanogap of different multipolar LSP modes. Polarization-dependent spectral measurements provide further insights into the exciton coupling with the local plasmon modes. Fig. 4a shows measured spectra at different detected polarizations, shifted, normalized, and plotted within the plasmon-exciton spectral region. Relative peak heights of the upper and lower plexciton contributions change as polarization angle evolves, qualitatively resembling anti-crossing behavior that is seen in a light-matter coupled system by detuning the energy of the LSP relative to the exciton. Our experimental study is fundamentally different, as it does not involve different members of a nanostructure ensemble that each have different plasmon resonances^{19,20,43,44}. The energy of the LSP has not been really tuned in our setup.

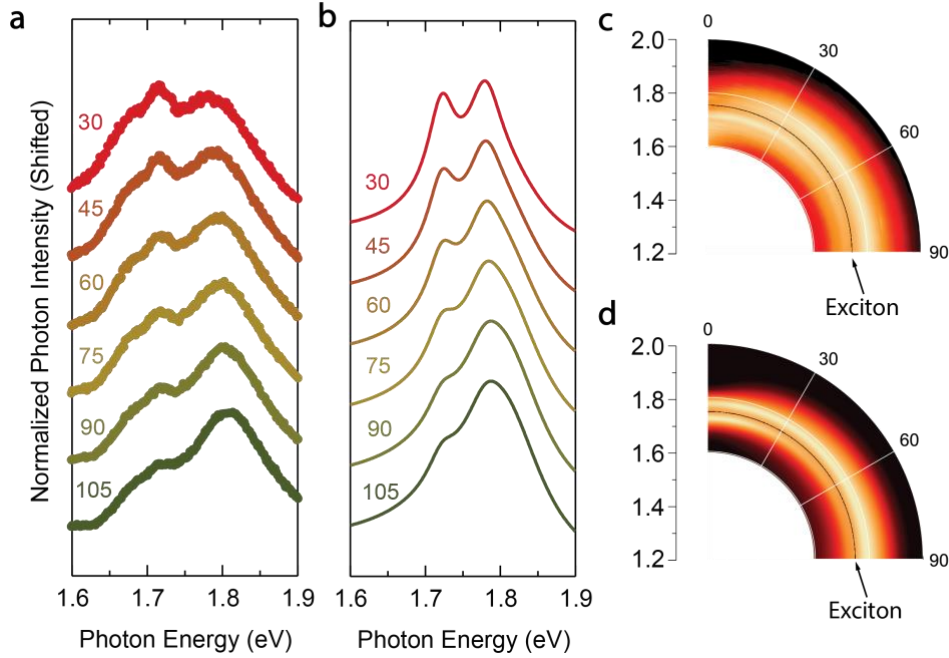


Figure 4. Spectral measurements of polarized EL spectra for the hybrid TMD on gap structure and numerical emission spectrum. (a) Normalized EL spectra at fixed bias 0.8V with a zero-bias junction conductance of $0.09G_0$ at different detection polarizations. (b) Calculated polarized spectra based on the simplified model involving coupling between the exciton and one of two optical modes. (c)-(d) Color plot of measured polarized spectra (normalized intensity) from 0 to 90 degree detected polarization and as a function of photon energy (c) together with numerical results for the electric field intensity (d). The polarization angle 0 degrees is defined to be parallel to the nanowire. The polaritonic dip in the spectra is observable in panels (c, d) at the appropriate energy (radial distance ≈ 1.73 eV).

To theoretically reproduce the experimental polarization dependent spectra, we need to incorporate an additional surface plasmon mode into our modelling. The polarized EL spectra as depicted in Fig. 4a can be then understood as the interaction between a TMD exciton and a LSP mode, together with the emission by a weakly confined, guided surface plasmon mode. Only the LSP was accounted for in our EM simulations. It lies in the exciton energy range (around 1.6 eV), and its coupling to the TMD exciton leads to doublet-line feature in Figs. 2a (experiment) and 3a (theory). The guided surface plasmon mode is blue-tuned and decoupled from the TMD exciton (See SI section 3.). It is generated at the tunnelling junction and propagates away from it via the gold nanowire and electrodes. Note that the propagation lengths of surface plasmons in gold stripes is of the order of 10 microns⁴⁵. The far-field emission of this guided mode cannot be described by

our EM calculations, as simulation volume ranged only up to 2 microns. To deal with the different length scales in the experimental samples, we built a toy model based on a master equation formalism that accounts for all radiative losses. We assumed a perturbative, static excitation that only populates the plasmonic modes and not the TMD exciton. Polarized far field photon spectra are then obtained through the Fourier transform of the two-time electric-field correlator (details of the derivation can be found in Methods). Figure 4b shows that the anti-crossing-like polarization behavior is perfectly traced out by this model. A detailed contour plot for numerical polarized intensity from 0 to 90 degree is plotted together with experiment results, showing good consistency (Fig. 4d and 4e). The full polar map both for experiment and numerical results are shown in Fig. S5.

The polaritonic electroluminescence spectrum from the hybrid TMD-gap system combined with numerical results shows that the onset of strong plasmon-exciton coupling can be reached in this geometry and detected through the EL process. The richness of the experimental plasmonic spectrum shapes the polarization dependence of the far-field plexcitonic EL spectrum. These results open avenues for fabricating novel on-chip electroluminescent heterostructure devices that leverage and control plasmon-exciton coupling through proper nanoscale geometric engineering. This is also a demonstration that plexcitonic effects, by determining the local photonic density of states, can be designed to manipulate the energetic relaxation of hot carriers in the metals supporting surface plasmons.

Methods

Device fabrication

The fabrication of the nanowire devices starts with a Si wafer that has 300 nm thick thermal oxide on top. The nanowires were first patterned using standard e-beam lithography. Briefly, double layer PMMA (495/950 combination) e-beam resist was applied to provide an undercut cross-section profile after development to ensure clean lift off the pure gold (18 nm thick) after evaporation (without any adhesion layer to improve the plasmonic performance and maximize the local density of photonic states^{23,46}). The wire dimensions are pre-determined so that the nanostructure supports plasmon modes that are resonant in the energy range of the TMD excitons (for WSe₂ at ~ 1.7 eV, 18 nm thick, 120 nm wide, 600 nm long). Each nanowire is connected to bow tie-shaped fan outs with long extended electrodes (150 μm), to facilitate wire bonding and the few-layer WSe₂ dry transfer process. WSe₂ flakes with various thicknesses are mechanically exfoliated onto a polydimethylpolysiloxane (PDMS) stamp and located using an optical microscope. WSe₂-coupled nanowires are then formed by employing a dry transfer method to drop down the selected WSe₂ on top of the nanowire to create the final device for strong-coupling measurements. The TMD on top of the nanogap will crack when the electrical bias across the gap exceeds 1.6 V during the measurement of EL spectrum possibly due to increased Joule heating, as can be seen in Fig. S1 of the supplemental information. Therefore, all the EL measurements are performed below 1.2V bias to keep the whole TMD-nanogap hybrid system intact.

Nanogap formation

The fabricated arrays of nanowire samples were mounted into a high vacuum ($\sim 10^{-9}$ mbar) optical cryostat. Initially at a substrate temperature of 80 K and then again at 30 K, the

electromigration technique²³ was applied to form a sub nanometer sized gap within the nanowire device. Specifically, cycles of voltage (0 to 1 V sweep) were applied across the nanowire and halted when a sharp drop (>5%) recorded in the current flowing in the nanowire. Subsequently, the same process was repeated until the conductance drops slightly below $1 G_0 = 2e^2/h$ (to ensure the formation of the tunnel junction), followed by the EL and PL measurements of the prepared device.

Optical measurements

A 100× long working distance objective with NA of 0.7 was used to collect photon emission from the biased TMD-nanowire devices. The emitted photons were guided through free space optics based on a home-built Raman spectroscopy setup⁴⁷ and focused onto a Si CCD spectrometer (Horiba iHR 320) for data collection. The spectra shown in all the figures are already corrected for the energy-dependent quantum efficiency of the CCD. PL spectra of the TMD was excited by a CW 532 nm laser through the collecting objective, and the map scan was performed through a lens mounted on a piezo, so that the focal spot was scanned with tens of nanometer precision.

Theoretical modelling and computational techniques

Numerical simulations

To gain insight into the electromagnetic resonances supported by the junction and how these couple to the TMD excitons, we have performed numerical simulations in the Maxwell's Equation solver in COMSOL Multiphysics. The nanojunction is composed by a 600 nm long and 120 nm wide gold strip. It is connected at the edges to electronic contacts that branch out at 45 degrees. To create the nanojunction, we cut the strip at an angle of 14° and create a gap of 14 nm. This gap is created at a lateral offset of 190 nm from the center of the strip to break the symmetries, as in the

experimental samples. We then add two half cylinders of 5 nm radius to each of the faces of the cut to create a pico-cavity with a minimum gap distance between the cylinders of 4 nm. The metallic structure has a height of 18 nm. To simulate the tunneling current, we place a dipolar source at the center of the 4 nm gap and set the dipole moment pointing from one face of the gap to the other. The metallic structure material is set to gold described by the permittivity given by⁴⁰. The gold structure is set over a substrate made of SiO₂ described by a refractive index of 1.5. On top of the metallic junction, we place a 5 nm layer of WSe₂, described by the permittivity given in the main text. On top of the WSe₂ we have air ($n = 1$). The total simulation domain is a sphere of 1 μm radius centered around the source dipole position and is terminated by a scattering boundary condition. To obtain the detected intensity we calculate the radiative Purcell, $P_R(\omega)$, or the local density of radiative states, obtained by integrating the time-averaged Poynting vector along the vertical (top) direction. According with the phenomenological expression presented in the main text, the far-field intensity is then obtained as

$$I_{FF} \propto \omega^4 P_R(\omega) e^{-\frac{\hbar\omega}{k_B T}},$$

with an effective temperature of 2000 K, in agreement with the experimental estimates.

Two mode coupling model

To fully capture the far-field experimental phenomenology we have developed a model. This is meant to reproduce experimental features that, according to our numerical simulations, are not related to the strong light-matter interactions that take place within the micron-sized volume around the nanowire junction. In particular, the model allows us to introduce a far-field maximum observed in the experiment, blue-detuned from the TMD exciton frequency, that we link to the

strong radiation losses experienced by the surface plasmon waves that scatter at the nanowire edges, microns away from the region of electron tunnelling. By construction, this maximum is absent in the numerical simulations, where the lateral boundary conditions prevent any power radiation in the vertical direction originated from propagating surface plasmons.

In our model, we have included two optical modes, and the exciton transition. The Hamiltonian that describes the interaction and pumping of the system is given by, $H = H_0 + H_{pump}$, with

$$H_0 = \hbar\omega_1 a_1^\dagger a_1 + \hbar\omega_\sigma \sigma^\dagger \sigma + \hbar g (a_1^\dagger \sigma + a_1 \sigma^\dagger) + \hbar\omega_2 a_2^\dagger a_2,$$

$$H_{pump} = \hbar\nu_1 (a_1^\dagger + a_1) + \hbar\nu_2 (a_2^\dagger + a_2),$$

where a_1 is the bosonic annihilation operator for the optical mode around 1.8 eV that our COMSOL simulations reproduce, the one responsible for the coupling to the exciton (where σ is the excitonic annihilation operator). Both are coupled through a Jaynes-Cummings term with strength g . On the other hand, a_2 is the annihilation operator for the exciton-decoupled, blue-detuned mode observed in the experiments. The electron static-like current couples to both optical modes, and not the TMD excitons, with relative strengths given by ν_i . Assuming that the pumping is small, and in order to account for optical and excitonic radiative decay⁶, we build an effective non-hermitian Hamiltonian of the form

$$H_{eff} = H_{pump} + \hbar\Omega_1 a_1^\dagger a_1 + \hbar\Omega_\sigma \sigma^\dagger \sigma + \hbar g (a_1^\dagger \sigma + a_1 \sigma^\dagger) + \hbar\Omega_2 a_2^\dagger a_2,$$

where $\Omega_i = \left(\omega_i - \frac{i\gamma_i}{2}\right)$ and, in the same fashion, $\Omega_\sigma = \left(\omega_\sigma - \frac{i\gamma_\sigma}{2}\right)$. Note that the γ 's are the radiative decay rates of the different elements of the system. We can diagonalize the terms that

couple the optical mode a_1 and the exciton σ above. These give rise to the polaritons observed experimentally. The polaritonic Hamiltonian is then given by $H_{pol} = \hbar\Omega_1 a_1^\dagger a_1 + \hbar\Omega_\sigma \sigma^\dagger \sigma + \hbar g(a_1^\dagger \sigma + a_1 \sigma^\dagger)$, and is diagonalized as $H_{pol}|N, \pm\rangle = \hbar\Omega_\pm(N)|N, \pm\rangle$, with $\Omega_\pm(N) = N\Omega_1 - \Delta \pm \sqrt{\Delta^2 + Ng^2}$, and

$$|N, \pm\rangle = \frac{g\sqrt{N}|n, g\rangle + (\Delta \mp \sqrt{\Delta^2 + Ng^2})|n-1, e\rangle}{\sqrt{Ng^2 + |\Delta \mp \sqrt{\Delta^2 + Ng^2}|^2}} \equiv A_\pm|n, g\rangle + B_\pm|n-1, e\rangle,$$

where $\Delta = (\Omega_1 - \Omega_\sigma)/2$, and $|g\rangle$ and $|e\rangle$ correspond, respectively, to the ground and excited state of the exciton, and $|n\rangle$ (where $n = N$) is the number of photons in mode a_1 . Then, one can treat the pump term using first-order perturbation theory, and find the perturbed ground state of the system, which turns out to be

$$|0'\rangle \approx |0, g\rangle \otimes |0\rangle_2 - v_1 \left(\left[\frac{A_+^*}{\Omega_+^*} |1, +\rangle + \frac{A_-^*}{\Omega_-^*} |1, -\rangle \right] \otimes |0\rangle_2 + \frac{v_2}{\Omega_2^* v_1} |0, g\rangle \otimes |1\rangle_2 \right).$$

Once this perturbed ground state is known, we can compute the power spectrum (under weak-pumping), given by

$$I(\omega) = Re \left(\lim_{T \rightarrow \infty} \frac{1}{2\pi T} \int_{-T/2}^{T/2} dt \int_{-\infty}^{\infty} d\tau \langle 0' | \xi^\dagger(t) \xi(t-\tau) | 0' \rangle e^{-i\omega\tau} \right),$$

where $\xi = \vec{\mu}_i a_i$, with $\vec{\mu}_i$ being the effective dipole moment of the optical modes. We assume that detected emission mainly comes from the optical modes, and since the pumping is incoherent, we

consider separately the intensity emitted by each optical mode (thus neglecting cross-correlation terms). The lineshapes for both modes are therefore

$$I_1(\omega) = \frac{1}{2\pi} |\nu_1 \mu_1|^2 \left(\left| \frac{A_+^2}{\Omega_+} \right|^2 \frac{|\Gamma_+|}{(\omega - \omega_+)^2 + \Gamma_+^2} + \left| \frac{A_-^2}{\Omega_-} \right|^2 \frac{|\Gamma_-|}{(\omega - \omega_-)^2 + \Gamma_-^2} \right),$$

$$I_2(\omega) = \frac{1}{2\pi} |\nu_2 \mu_2|^2 \left| \frac{1}{\Omega_2} \right|^2 \frac{|\Gamma_2|}{(\omega - \omega_2)^2 + \Gamma_2^2},$$

where $\omega_i = \text{Re}(\Omega_i)$, and $\Gamma_i = \text{Im}(\Omega_i)$. Finally, the measured intensity is given by the projection of the far field amplitude over the polarizer, which can be calculated as

$$I_T(\omega) = I_1(\omega) \cos^2(\phi - \phi_1) + I_2(\omega) \cos^2(\phi - \phi_2),$$

where ϕ is the polarizer angle and ϕ_i is the orientation of the dipole moment of mode i . We set the parameters of the TMD exciton and first cavity mode to the values obtained from our numerical simulations: $\phi_1 = 45^\circ$, $\omega_1 = 1.75$ eV, $\gamma_1 = 2\Gamma_1 = 90$ meV, $g = 35$ meV, $\omega_\sigma = 1.75$ eV, $\gamma_\sigma = 10$ meV. For the second cavity mode, we take $\omega_2 = 1.81$ eV, $\gamma_2 = 2\Gamma_2 = 140$ meV, $\phi_2 = 90^\circ$. The other free parameter is the ratio $f = |\nu_2 \mu_2 / \nu_1 \mu_1|^2$, which weights how much more (or less) the two different cavity modes get excited in the near field by the tunneling current (ν_2 / ν_1), and how relatively bright they are (μ_2 / μ_1). These two mechanisms are indistinguishable from the far field. We know from experimental data that the a_2 mode is much brighter, so we have set $f = 3$, with which we produce the results shown in the main text.

Data Availability

The data sets used in this study are available at Zenodo (insert URL).

Code Availability

The analysis codes that support the findings of the study are available from the corresponding authors on reasonable request.

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ASSOCIATED CONTENT

Supporting Information.

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Author Contributions

D.N., J.Y. and Y.Z. designed the experiment. J.Y. and Y.Z. fabricated the devices, conducted the experiment, and modelled the data. F.J.G.-V., A.I.F.-D. and J.A.-A. theoretically analyzed and numerically modeled the experimental polaritonic light emission spectra and polarized coupling spectra. All authors wrote the manuscript and have given approval to the final version of the manuscript.

Notes

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